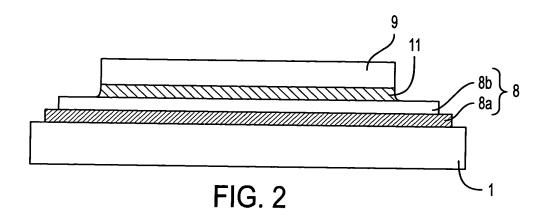
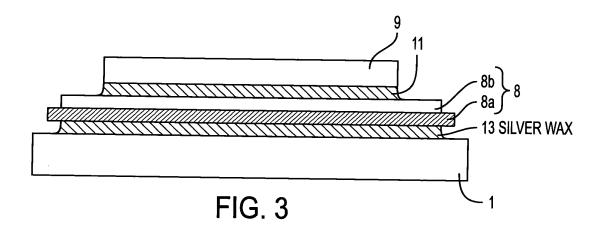
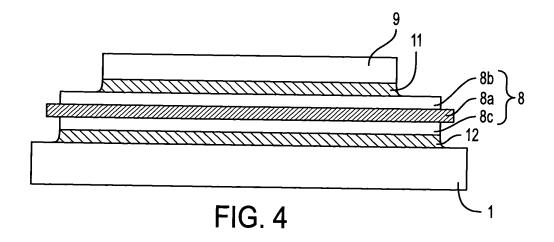


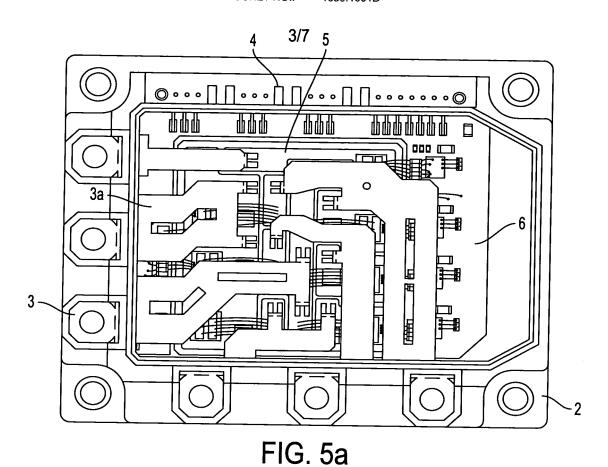
FIG. 1b







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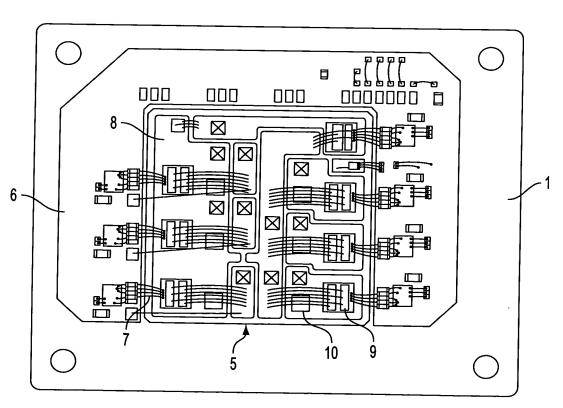


FIG. 5b

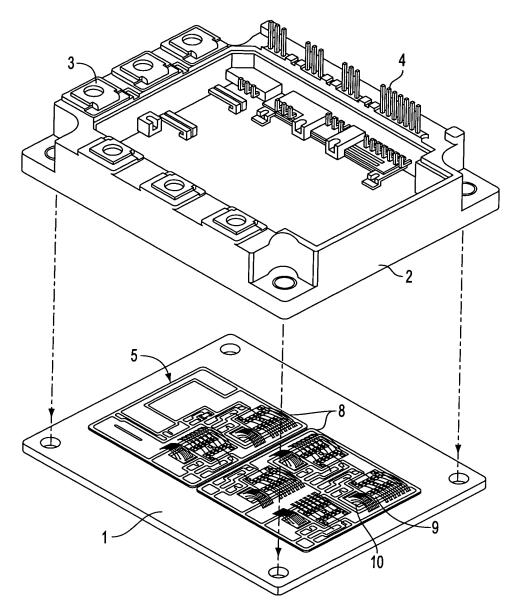


FIG. 6a

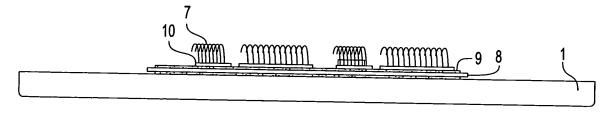


FIG. 6b

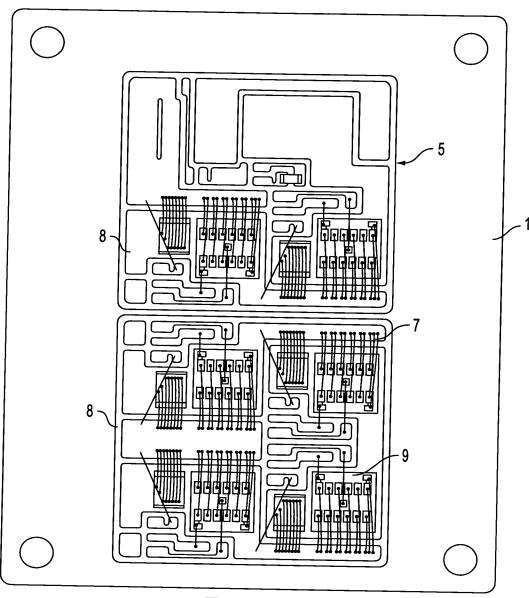


FIG. 7a

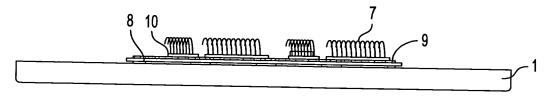
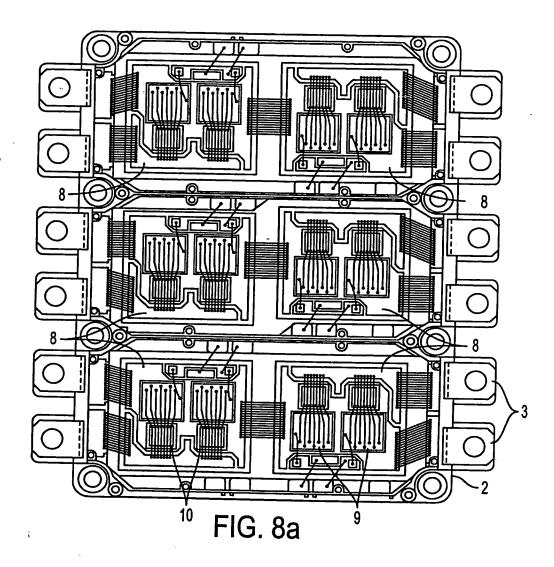
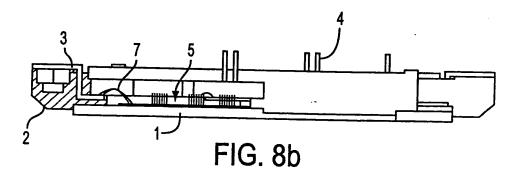


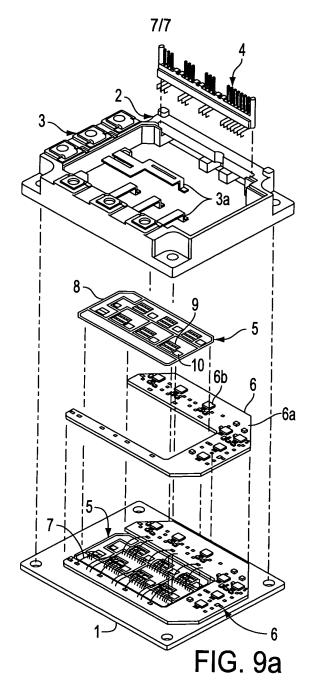
FIG. 7b

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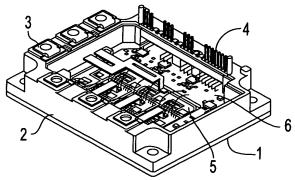


FIG. 9b